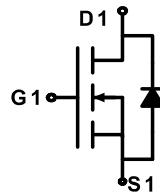


## Feature

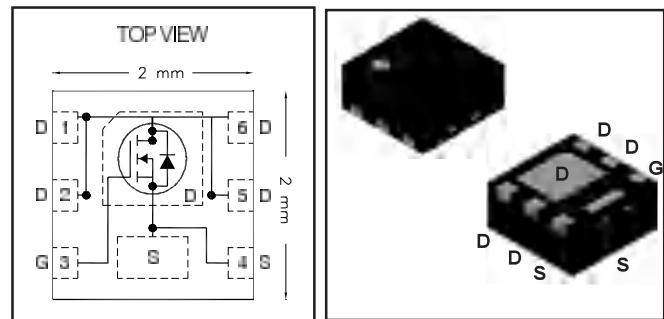
- 30V,5.8A  
 $R_{DS(on)} < 26m\Omega @ V_{GS}=10V$  TYP=18 mΩ  
 $R_{DS(on)} < 32m\Omega @ V_{GS}=4.5V$  TYP=23 mΩ
- Advanced Trench Technology
- Lead free product is acquired



Schematic diagram

## Application

- Interfacing Switching
- Load Switching
- Power management



## Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity (PCS) |
|----------------|--------|----------------|-----------|------------|----------------|
| 6324           | AP6324 | PDFN2*2        | 7 inch    | -          | -              |

## ABSOLUTE MAXIMUM RATINGS ( $T_a=25^\circ C$ unless otherwise noted)

| Parameter  | Symbol          | Value    | Unit |
|--|-----------------|----------|------|
| Drain-Source Voltage                                       | $V_{DS}$        | 30       | V    |
| Gate-Source Voltage  | $V_{GS}$        | $\pm 20$ | V    |
| Continuous Drain Current ( $T_a = 25^\circ C$ )            | $I_D$           | 5.8      | A    |
| Continuous Drain Current ( $T_a = 70^\circ C$ )            | $I_D$           | 3.8      | A    |
| Pulsed Drain Current                                       | $I_{DM}$        | 23       | A    |
| Power Dissipation  | $P_D$           | 1.47     | W    |
| Thermal Resistance from Junction to Ambient <sup>(4)</sup> | $R_{\theta JA}$ | 85       | °C/W |
| Junction Temperature                                       | $T_J$           | 150      | °C   |
| Storage Temperature  | $T_{STG}$       | -55~+150 | °C   |

**MOSFET ELECTRICAL CHARACTERISTICS( $T_a=25^\circ C$  unless otherwise noted)**

| Parameter                                 | Symbol        | Test Condition   | Min | Type | Max       | Unit      |
|---|---------------|--|-----|------|-----------|-----------|
| <b>Static Characteristics</b>             |               |  |     |      |           |           |
| Drain-source breakdown voltage            | $V_{(BR)DSS}$ | $V_{GS} = 0V, I_D = 250\mu A$                                | 30  | -    | -         | V         |
| Zero gate voltage drain current           | $I_{DSS}$     | $V_{DS} = 30V, V_{GS} = 0V$                                  | -   | -    | 1         | $\mu A$   |
| Gate-body leakage current                 | $I_{GSS}$     | $V_{GS} = \pm 20V, V_{DS} = 0V$                              | -   | -    | $\pm 100$ | nA        |
| Gate threshold voltage <sup>(3)</sup>     | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\mu A$                            | 1.0 | 1.5  | 2.5       | V         |
| Drain-source on-resistance <sup>(3)</sup> | $R_{DS(on)}$  | $V_{GS} = 10V, I_D = 5.8A$                                   | -   | 18   | 26        | $m\Omega$ |
|   |               | $V_{GS} = 4.5V, I_D = 3A$                                    | -   | 23   | 32        |           |
| <b>Dynamic characteristics</b>            |               |  |     |      |           |           |
| Input Capacitance                         | $C_{iss}$     | $V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$                        | -   | 490  | -         | pF        |
| Output Capacitance                        | $C_{oss}$     |  | -   | 79   | -         |           |
| Reverse Transfer Capacitance              | $C_{rss}$     |  | -   | 61   | -         |           |
| <b>Switching characteristics</b>          |               |  |     |      |           |           |
| Turn-on delay time                        | $t_{d(on)}$   | $V_{DD} = 15V, I_D = 3A,$<br>$V_{GS} = 4.5V, R_G = 10\Omega$ | -   | 4.5  | -         | ns        |
| Turn-on rise time                         | $t_r$         |  | -   | 2.5  | -         |           |
| Turn-off delay time                       | $t_{d(off)}$  |  | -   | 14.5 | -         |           |
| Turn-off fall time                        | $t_f$         |  | -   | 3.5  | -         |           |
| Total Gate Charge                         | $Q_g$         | $V_{DS} = 15V, I_D = 5.8A,$<br>$V_{GS} = 4.5V$               | -   | 5.2  | -         | nC        |
| Gate-Source Charge                        | $Q_{gs}$      |  | -   | 0.9  | -         |           |
| Gate-Drain Charge                         | $Q_{gd}$      |  | -   | 1.3  | -         |           |
| <b>Source-Drain Diode characteristics</b> |               |  |     |      |           |           |
| Diode Forward voltage <sup>(3)</sup>      | $V_{DS}$      | $V_{GS} = 0V, I_S = 5.8A$                                    | -   | -    | 1.2       | V         |
| Diode Forward current <sup>(4)</sup>      | $I_S$         |  | -   | -    | 5.8       | A         |

**Notes:**

1. Repetitive Rating: pulse width limited by maximum junction temperature
2. Pulse Test: pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2\%$
3. Surface Mounted on FR4 Board,  $t \leq 10$  sec

## Test Circuit

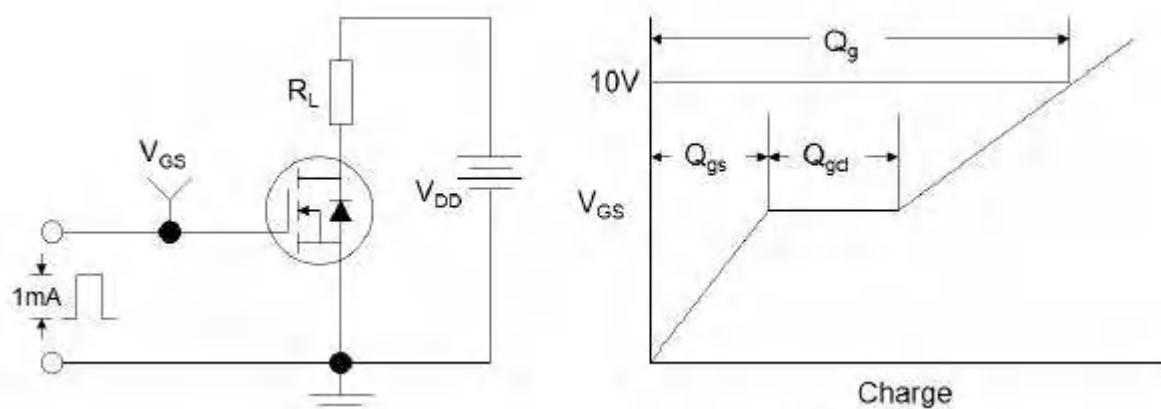


Figure1:Gate Charge Test Circuit & Waveform

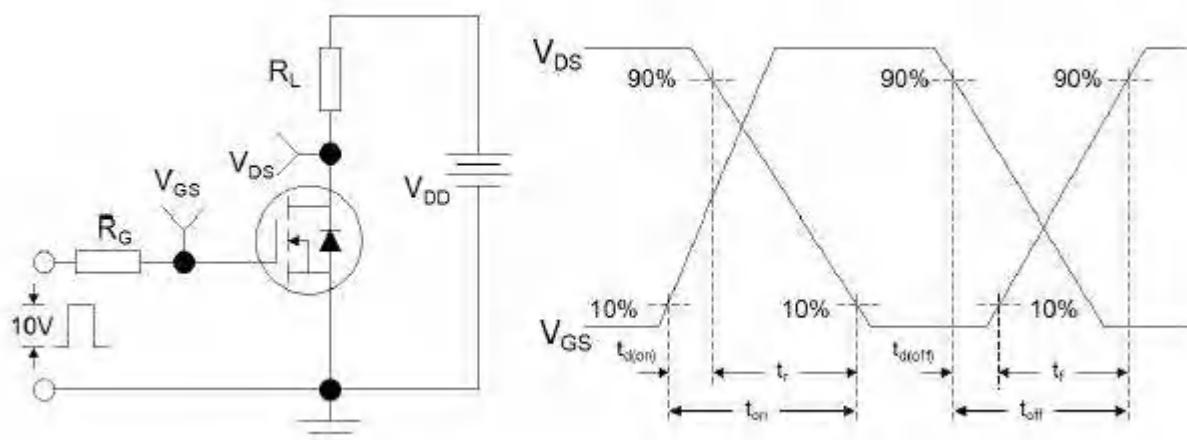


Figure 2: Resistive Switching Test Circuit & Waveforms

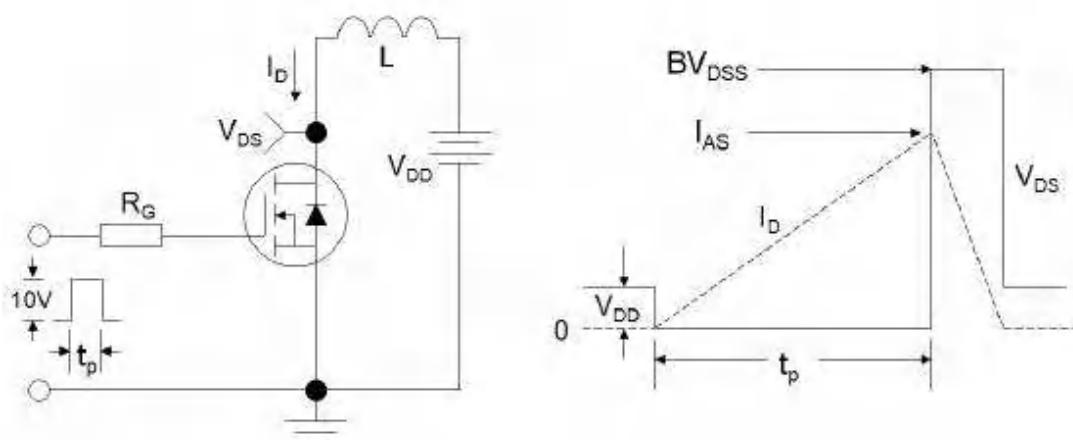
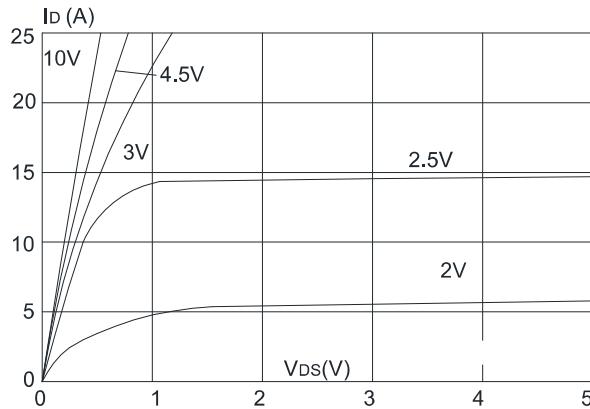
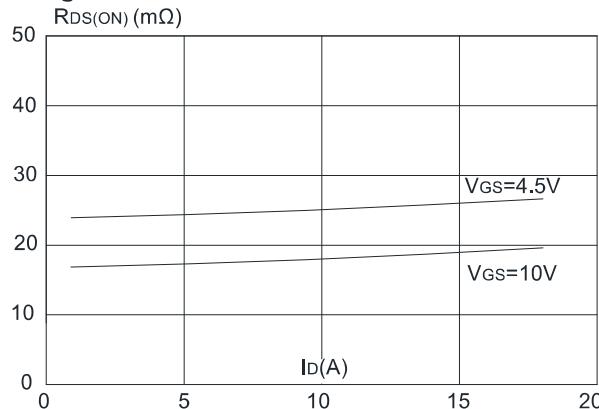


Figure 3:Unclamped Inductive Switching Test Circuit & Waveforms

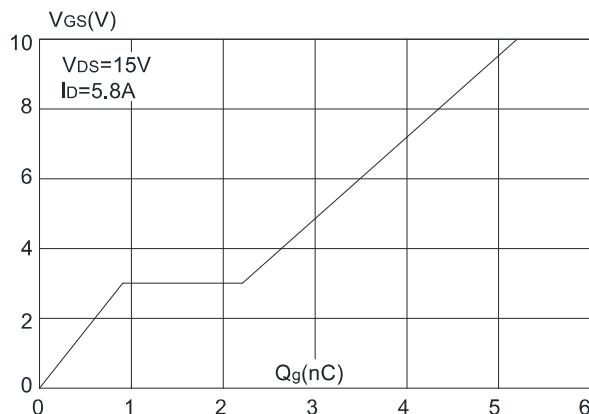
**Figure1:** Output Characteristics



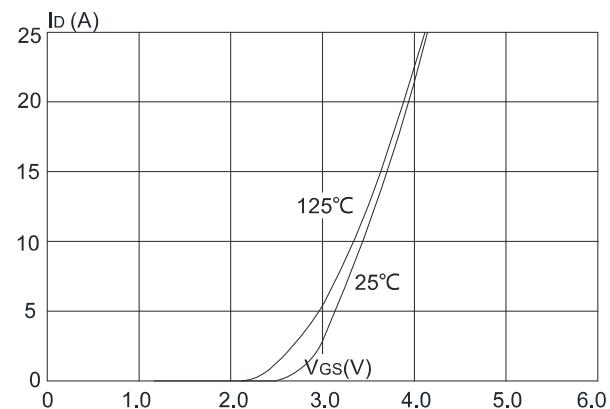
**Figure 3:** On-resistance vs. Drain Current



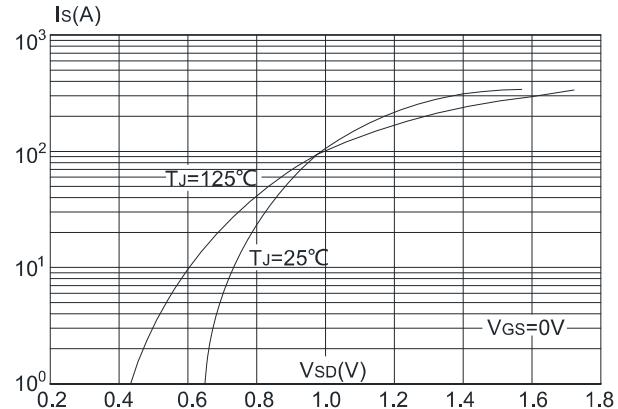
**Figure 5:** Gate Charge Characteristics



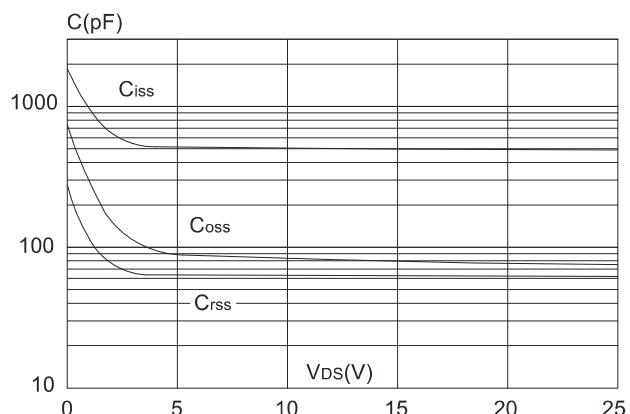
**Figure 2:** Typical Transfer Characteristics



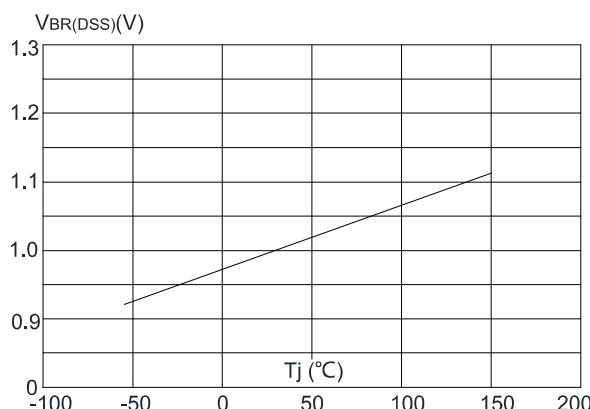
**Figure 4:** Body Diode Characteristics



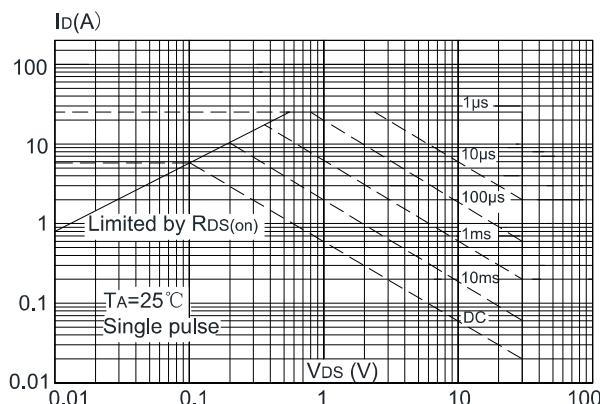
**Figure 6:** Capacitance Characteristics



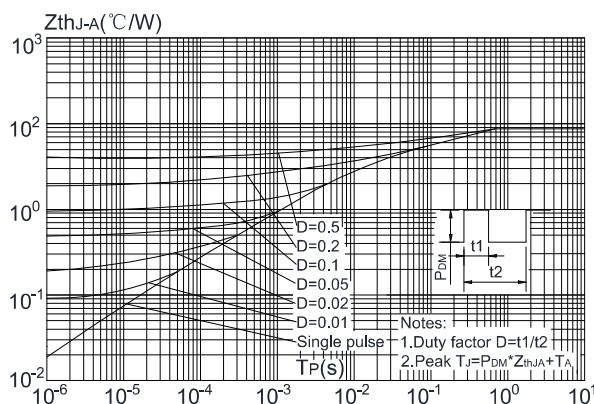
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



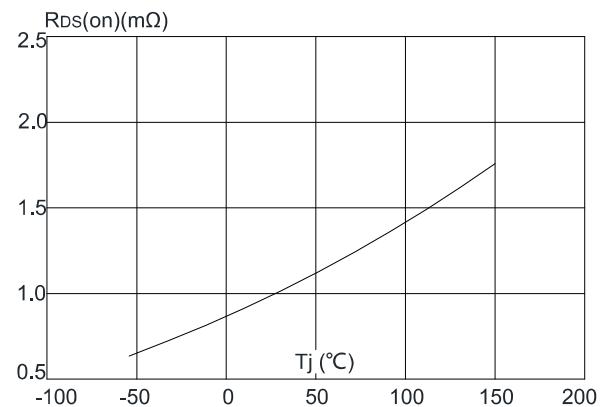
**Figure 9:** Maximum Safe Operating Area



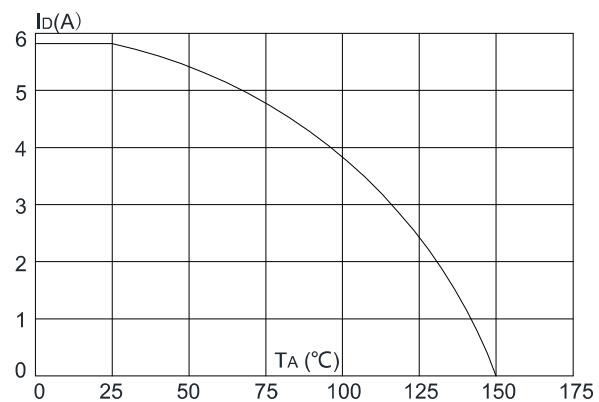
**Figure.11:** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



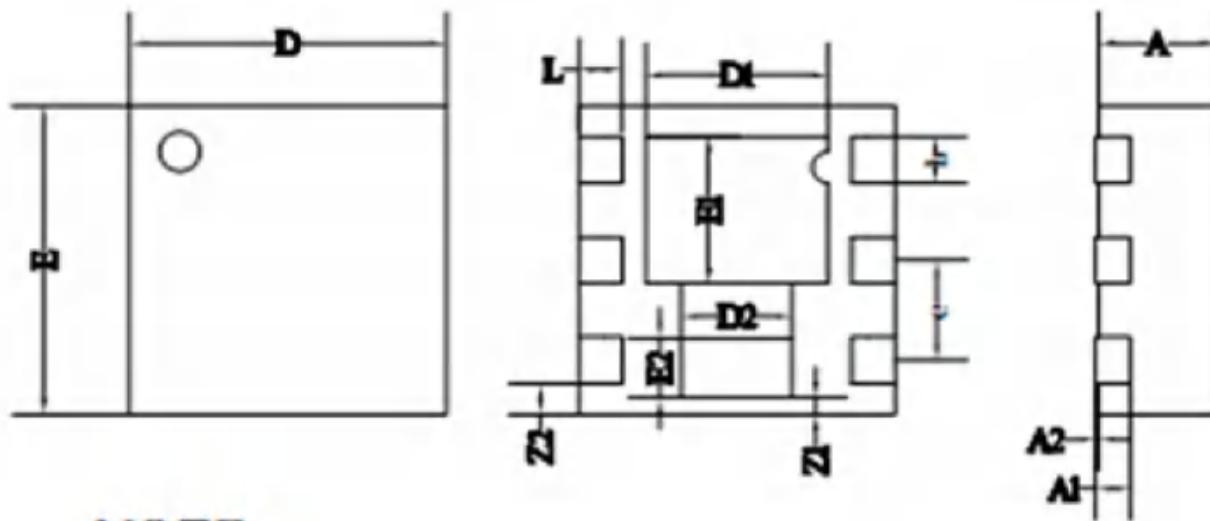
**Figure 8:** Normalized on Resistance vs. Junction Temperature



**Figure 10:** Maximum Continuous Drain Current vs. Ambient Temperature



## Package Information



**NOTE:**  
**All dimensions are in mm**

|    | MIN      | NOM   | MAX  |
|----|----------|-------|------|
| D  | 1.95     | 2.00  | 2.05 |
| E  | 1.95     | 2.00  | 2.05 |
| D1 | 1.10     | 1.15  | 1.20 |
| E1 | 0.90     | 0.95  | 1.00 |
| D2 | 0.65     | 0.70  | 0.75 |
| E2 | 0.33     | 0.38  | 0.43 |
| L  | 0.23     | 0.275 | 0.33 |
| b  | 0.25     | 0.30  | 0.35 |
| e  | 0.65BSC  |       |      |
| A  | 0.45     | 0.50  | 0.55 |
| A1 | 0.150REF |       |      |
| A2 | 0.00     | -     | 0.05 |
| Z1 | 0.06     | 0.11  | 0.16 |
| Z2 | 0.15     | 0.20  | 0.25 |